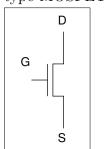
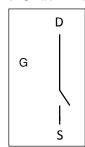
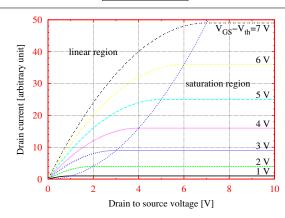
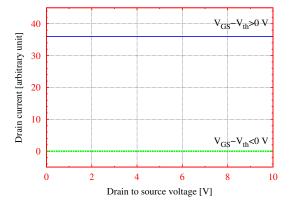
N-type MOSFET



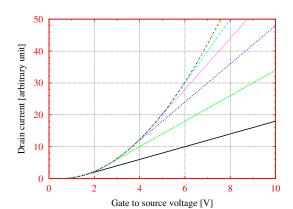
Zero-Order Model

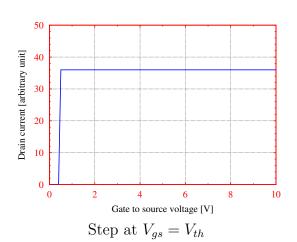






 $I_{ds}$  unbounded when  $V_{gs} > V_{th}$ 



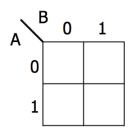


(even this is a simplified approximation)

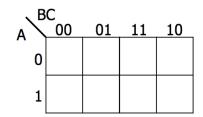
	NMOS	PMOS	
Threshold	$V_{thn} > 0$	$V_{thp} < 0$	
		$V_{thp} pprox -V_{thn}$	
Conduct	positive input	negative input	
	$V_{gs} > V_{thn}$	$V_{gs} < V_{thp}$	
Drain	most positive terminal	most negative terminal	
Source	most negative terminal	most positive terminal	
	(source of electrons)	(source of holes)	

$$V_{gs} = V_g - V_s \tag{1}$$

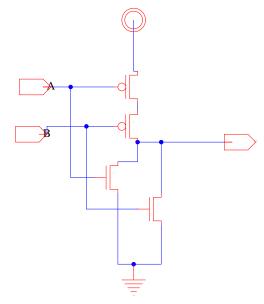
1. Simplify the boolean expression  $Z = \overline{A} \cdot \overline{B} + A \cdot \overline{B} + \overline{A} \cdot B$  to the minimum sum of products with the 2-variable K-map:



2. Simplify the boolean expression  $Z = \overline{A} \cdot \overline{B} \cdot \overline{C} + \overline{A} \cdot B + A \cdot B \cdot \overline{C} + A \cdot C$  to the minimum sum of products with the 3-variable K-map:



- 3. What function does this circuit implement? (inputs are a and b)
  - [N.B. crossing wires with no dot are **not** connected.]

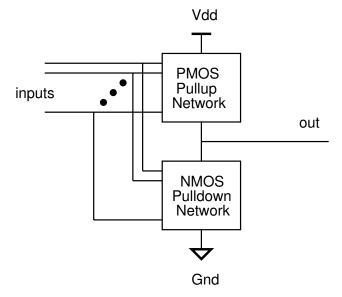


4. If  $\overline{f} = a + b$ , what is f in minimum-sum-of-products form?

[N.B. 
$$\overline{f} = \sim f = /f = (\text{not } f) = f$$
']

5. Design gate to perform:  $f = (\overline{a} + \overline{b}) \cdot \overline{c}$ 

General form for Static CMOS Gate:



6. Extra practice for outside of class: Simplify the boolean expression  $Z = A \cdot B \cdot C + A \cdot B \cdot \overline{C} + \overline{A} \cdot B \cdot C$  to the minimum sum of products with the 3-variable K-map:

A B	C _00	01	11	10
0				
1				

Simplify the truth table to the minimum sum of products with the 4-variable K-map:

I	,			
Α	В	С	D	Z
0	0	0	0	1
0	0	0	1	1
0	0	1	0	1
0	0	1	1	1
0	1	0	0	1
0	1	0	1	1
0	1	1	0	1
0	1	1	1	1
1	0	0	0	0
1	0	0	1	1
1	0	1	0	0
1	0	1	1	1
1	1	0	0	0
1	1	0	1	0
1	1	1	0	0
1	1	1	1	0